# SENSITRON SEMICONDUCTOR

SHD126145 SHD126145P SHD126145N SHD126145D

TECHNICAL DATA DATA SHEET 5117, REV. A.3

# SCHOTTKY RECTIFIER 175°C Operating Temperature

# **Applications:**

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

# Features:

- Soft reverse recovery at low and high temperature
- Low forward voltage drop
- Low power loss, high efficiency
- High surge capacity
- Guard ring for enhanced durability and long term reliability
- Guaranteed reverse avalanche characteristics
- Out performs 150 Volt ultrafast rectifiers
- For ceramic seals use part number prefix SHDC

## **Maximum Ratings:**

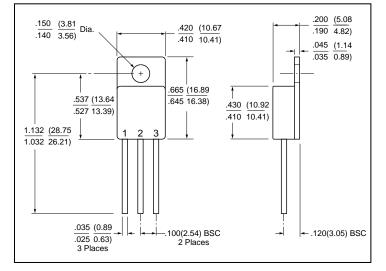
Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V <sub>RWM</sub>	-	150	V
Max. Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle, rectangular wave form (Single & Doubler)	7.5	A
Max. Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle, rectangular wave form (Common Cathode, Common Anode)	15	A
Max. Peak One Cycle Non- Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine wave pulsed (per leg)	75	A
Max. Thermal Resistance	$R_{ ext{ heta}JC}$	(per leg)	5.37	°C/W
Max. Junction Temperature	TJ	-	-55 to +175	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-65 to +175	О°

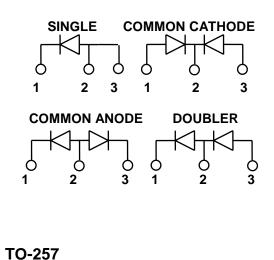
# **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V <sub>F1</sub>	@ 7.5A, Pulse, T <sub>J</sub> = 25 °C	0.95	V
		(per leg)		
	$V_{F2}$	@ 7.5A, Pulse, T <sub>J</sub> = 125 °C	0.86	V
		(per leg)		
Max. Reverse Current	I <sub>R1</sub>	@V <sub>R</sub> = 150V, Pulse,	0.25	mA
		$T_J = 25 \ ^{\circ}C \ (per \ leg)$		
	I <sub>R2</sub>	@V <sub>R</sub> = 150V, Pulse,	4.0	mA
		T <sub>J</sub> = 125 °C (per leg)		
Max. Junction Capacitance	CT	@V <sub>R</sub> = 10V, T <sub>C</sub> = 25 °C	250	pF
		f <sub>SIG</sub> = 1MHz,		
		$V_{SIG} = 50 \text{mV} (p-p) (per leg)$		

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#### Mechanical Dimensions: In Inches / mm

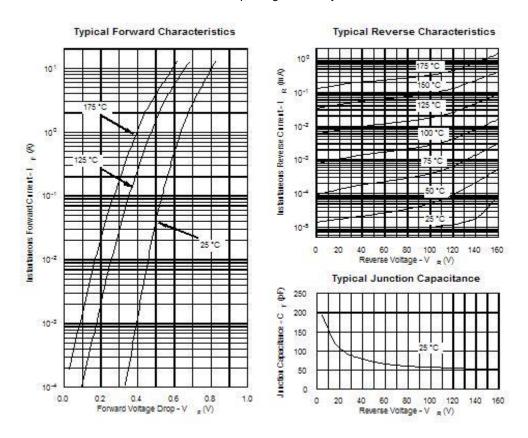




#### **PINOUT TABLE**

TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
DUAL RECTIFIER, COMMON CATHODE (P)	ANODE 1	COMMON CATHODE	ANODE 2
DUAL RECTIFIER, COMMON ANODE (N)	CATHODE 1	COMMON ANODE	CATHODE 2
DUAL RECTIFIER, DOUBLER (D)	ANODE	ANODE/CATHODE	CATHODE

Note: The Vf curves shown are for the SD090SC150 unpackaged die only.



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#### SENSITRON

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#### **PART ORDERING INFORMATION:**

	SHD <u>126</u>	<u>6145</u> ↓	<u>XX</u> X
	Part	Number	
Screening	g Level (blank is no screening):		
Suffix	Screened in Accordance with:		
blank	No screening level		
SX*	MIL-PRF-19500, TX Level		
SV*	MIL-PRF-19500, TXV Level	←	
SS*	MIL-PRF-19500, S Level		
	k is no QCI):		
Suffix	Inspection in Accordance with:		
blank	No QCI		
Q*	MIL-PRF-19500 QCI		

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